NSN 5961-01-528-6119

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Inclosure Material:

Plastic

Overall Length:

Between 1.496 inches and 1.505 inches

Overall Width:

Between 0.990 inches and 1.001 inches

Mounting Facility Quantity:

2

Mounting Method:

Slot and unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source

Current Rating Per Characteristic:

180.00 amperes source cutoff current of standard range

Power Rating Per Characteristic:

700.0 watts collector power dissipation peak

Product Name:

Hiperfet power mosfet

Special Features:

Single die mofset; n-channel enhancement mode

Terminal Type And Quantity:

4 screw

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0